

BAW33 Diodes

General Purpose Fast Rectifier

Military/High-Rel N

I(O) Max.(A) Output Current 225m

V(RRM)(V) Rep.Pk.Rev. Voltage 70

t(rr) Max.(s) Rev.Rec. Time 25n

@I(F) (A) (Test Condition) 200m

@I(R) (A) (Test Condition) 200m

V(FM) Max.(V) Forward Voltage 1.3

@I(FM) (A) (Test Condition) 350m

@V(RM) (V) (Test Condition)

I(RM) Max.(A) Reverse Current .20u

@V(R) (V)(Test Condition)

I(RM) Max.(A) Pk. Rev. Current

@V(R) (V) (Test Condition)

@Temp. (°C) (Test Condition)

Semiconductor Material Silicon

Maximum Operating Temp (°C) 175'

Package Style DO-35